

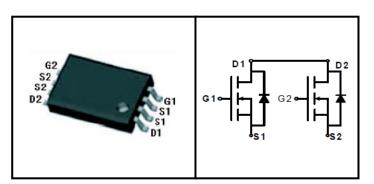
20V N-Channel Trench MOSFET

FEATURES

- Trench Power MOSFET Technology
- Low R_{DS(ON)}
- Low Gate Charge
- Optimized For Fast-switching Applications

APPLICATIONS

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial





Device Marking and Package Information				
Device	vice Package Markin			
TTK8205	TSSOP-8	8205		

Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted					
Deventer	Cumple of	Value			
Parameter	Symbol	TSSOP-8	Unit		
Drain-Source Voltage ($V_{GS} = 0V$)	V _{DSS}	20	V		
Continuous Drain Current	I _D	6	A		
Pulsed Drain Current (note1)	I _{DM}	24	А		
Gate-Source Voltage	V _{GSS}	±10	V		
Single Pulse Avalanche Energy (note2)	E _{AS}	7.4	mJ		
Avalanche Current	I _{AS}	7	А		
Power Dissipation ($T_c = 25^{\circ}C$)	P _D	1.5	W		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C		

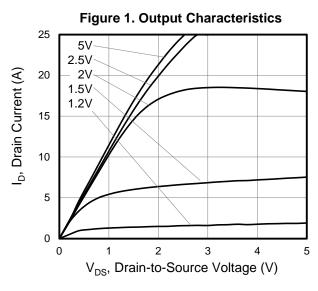
Thermal Resistance					
Peremeter	Ormshall	Value	Unit		
Parameter	Symbol	TSSOP-8	Unit		
Thermal Resistance, Junction-to-Case	R _{thJC}	14.4			
Thermal Resistance, Junction-to-Ambient	R _{thJA}	83	K/W		

Demonstration			Value				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 250\mu A$	20			V	
Zero Gate Voltage Drain Current	-	$V_{DS} = 20V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μΑ	
	I _{DSS}	$V_{DS} = 20V, V_{GS} = 0V, T_{J} = 150^{\circ}C$			100		
Gate-Source Leakage	I _{GSS}	$V_{GS} = \pm 10 V$			±100	nA	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.5	0.7	1.2	V	
		$V_{GS} = 10V, I_{D} = 3A$		16 20.5		mΩ	
Drain-Source On-Resistance (Note3)	R _{DS(on)}	$V_{GS} = 4.5 V, I_{D} = 3 A$		19	25	mΩ	
		$V_{GS} = 2.5 V, I_{D} = 3 A$		24	31.5	mΩ	
Forward Transconductance (Note3)	9 _{fs}	V _{DS} = 5V, I _D =3A		8		S	
Dynamic							
Input Capacitance	C _{iss})/0)/		408		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 10V,$		67			
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		24			
Tatal Oata Ohanna	Q _g (10V)			12		nC	
Total Gate Charge	Q _g (4.5V)	$V_{DD} = 10V, I_{D} = 6A,$		5.8			
Gate-Source Charge	Q_{gs}	$V_{DD} = 10V, I_D = 6A, \\ V_{GS} = 10V$		0.7			
Gate-Drain Charge	Q_{gd}			1.8			
Turn-on Delay Time	t _{d(on)}			15			
Turn-on Rise Time	t _r	$V_{DD} = 10V, I_{D} = 6A,$		17		ns	
Turn-off Delay Time	t _{d(off)}	$R_{\rm G} = 2.5\Omega$		42			
Turn-off Fall Time	t _f			40			
Drain-Source Body Diode Characteri	stics						
Continuous Body Diode Current	ا _s	T 0500			6		
Pulsed Diode Forward Current	I _{SM}	$T_{\rm C} = 25^{\circ}{\rm C}$			24	A	
Body Diode Voltage	V _{SD}	T _J = 25⁰C, I _{SD} = 6A, V _{GS} = 0V			1.2	V	

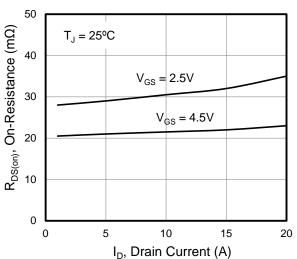
Notes

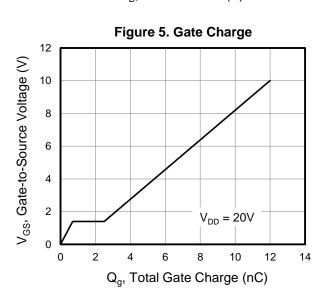
- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2. V_{DD} = 20V, R_{G} = 25 Ω , Starting T_{J} = 25°C
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 1%

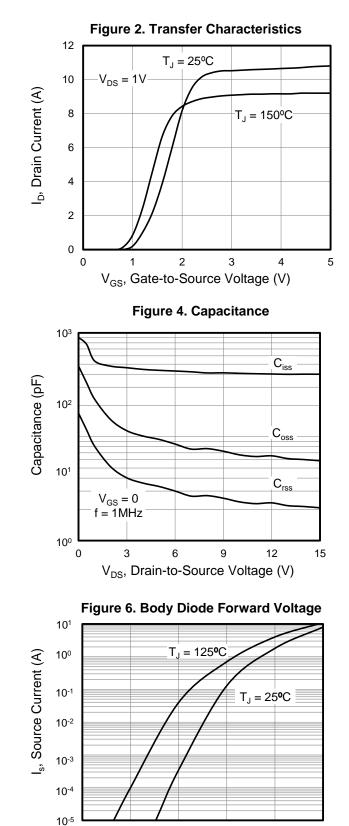
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted





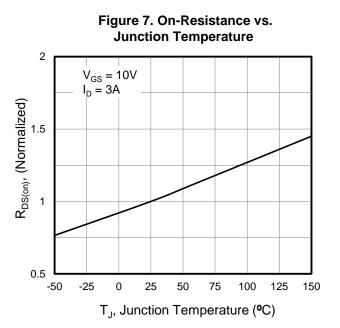






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Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted

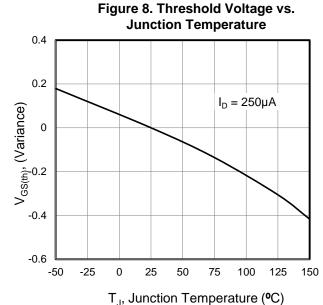
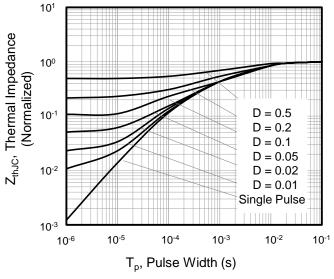
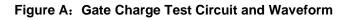


Figure 9. Transient Thermal Impedance





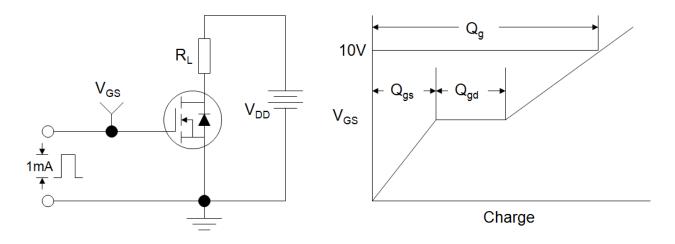


Figure B: Resistive Switching Test Circuit and Waveform

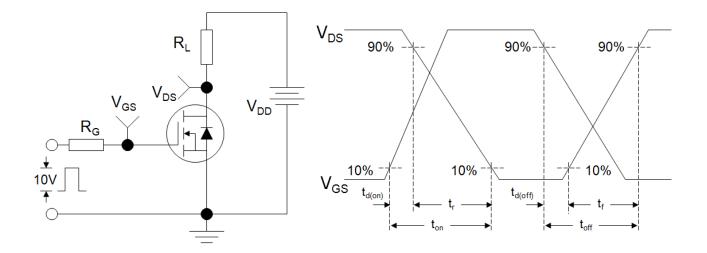
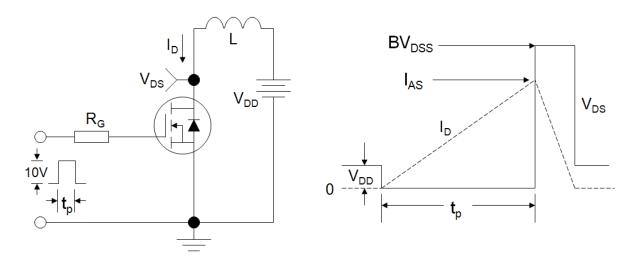


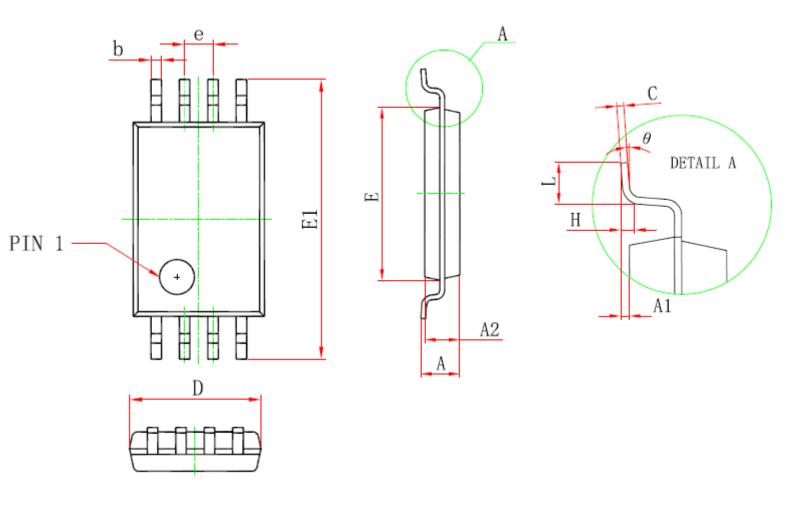
Figure C: Unclamped Inductive Switching Test Circuit and Waveform







TSSOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
D	2.900	3.100	0.114	0.122
E	4.300	4.500	0.169	0.177
ь	0.190	0.300	0.007	0.012
с	0.090	0.200	0.004	0.008
E1	6.250	6.550	0.246	0.258
А		1.200		0.047
A2	0.800	1.000	0.031	0.039
A1	0.050	0.150	0.002	0.006
e	0.65 (BSC)		0.026(BSC)	
L	0.500	0.700	0.020	0.028
Н	0.25(TYP)		0.01(TYP)	
θ	1°	7 °	1 °	7 °



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